**Vishay Semiconductors** 



# Silicon PIN Photodiode, RoHS Compliant



BPW83 is a PIN photodiode with high speed and high radiant

sensitivity in a black, side view plastic package with daylight

blocking filter. Filter bandwidth is matched with 870 nm to

## FEATURES

- Package type: leaded
- Package form: side view
- Dimensions (L x W x H in mm): 5 x 3 x 6.4
- Radiant sensitive area (in mm<sup>2</sup>): 7.5
- High radiant sensitivity
- Daylight blocking filter matched with 870 nm to 950 nm emitters
- · Fast response times
- Angle of half sensitivity:  $\phi = \pm 65^{\circ}$
- Lead (Pb)-free component in accordance with RoHS 2002/95/EC and WEEE 2002/96/EC

## **APPLICATIONS**

- · High speed detector for infrared radiation
- Infrared remote control and free air data transmission systems, e.g. in combination with TSFFxxxx series IR emitters

| PRODUCT SUMMARY |                      |                |                       |  |
|-----------------|----------------------|----------------|-----------------------|--|
| COMPONENT       | I <sub>ra</sub> (μΑ) | φ <b>(deg)</b> | λ <sub>0.5</sub> (nm) |  |
| BPW83           | 45                   | ± 65           | 790 to 1050           |  |

### Note

DESCRIPTION

950 nm IR emitters.

Test condition see table "Basic Characteristics"

| ORDERING INFORMATION |           |                              |              |  |
|----------------------|-----------|------------------------------|--------------|--|
| ORDERING CODE        | PACKAGING | REMARKS                      | PACKAGE FORM |  |
| BPW83                | Bulk      | MOQ: 4000 pcs, 4000 pcs/bulk | Side view    |  |

#### Note

MOQ: minimum order quantity

| ABSOLUTE MAXIMUM RATINGS            |                                              |                   |               |      |  |
|-------------------------------------|----------------------------------------------|-------------------|---------------|------|--|
| PARAMETER                           | TEST CONDITION                               | SYMBOL            | VALUE         | UNIT |  |
| Reverse voltage                     |                                              | V <sub>R</sub>    | 60            | V    |  |
| Power dissipation                   | $T_{amb} \le 25 \ ^{\circ}C$                 | Pv                | 215           | mW   |  |
| Junction temperature                |                                              | Тj                | 100           | °C   |  |
| Operating temperature range         |                                              | T <sub>amb</sub>  | - 40 to + 100 | °C   |  |
| Storage temperature range           |                                              | T <sub>stg</sub>  | - 40 to + 100 | °C   |  |
| Soldering temperature               | t ≤ 5 s                                      | T <sub>sd</sub>   | 260           | °C   |  |
| Thermal resistance junction/ambient | Connected with Cu wire, 0.14 mm <sup>2</sup> | R <sub>thJA</sub> | 350           | K/W  |  |

### Note

410

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T<sub>amb</sub> = 25 °C, unless otherwise specified

COMPLIANT



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| BASIC CHARACTERISTICS          |                                                                                     |                   |      |                       |      |        |
|--------------------------------|-------------------------------------------------------------------------------------|-------------------|------|-----------------------|------|--------|
| PARAMETER                      | TEST CONDITION                                                                      | SYMBOL            | MIN. | TYP.                  | MAX. | UNIT   |
| Breakdown voltage              | I <sub>R</sub> = 100 μA, E = 0                                                      | V <sub>(BR)</sub> | 60   |                       |      | V      |
| Reverse dark current           | $V_{R} = 10 V, E = 0$                                                               | I <sub>ro</sub>   |      | 2                     | 30   | nA     |
| Diode capacitance              | $V_{R} = 0 V, f = 1 MHz, E = 0$                                                     | CD                |      | 70                    |      | pF     |
|                                | $V_{R} = 3 V, f = 1 MHz, E = 0$                                                     | CD                |      | 25                    | 40   | pF     |
| Open circuit voltage           | $E_e = 1 \text{ mW/cm}^2$ , $\lambda = 870 \text{ nm}$                              | Vo                |      | 350                   |      | mV     |
| Short circuit current          | $E_e = 1 \text{ mW/cm}^2$ , $\lambda = 870 \text{ nm}$                              | l <sub>k</sub>    |      | 38                    |      | μA     |
| Reverse light current          | $E_e = 1 \text{ mW/cm}^2, \lambda = 870 \text{ nm}, V_R = 5 \text{ V}$              | I <sub>ra</sub>   | 43   | 45                    |      | μΑ     |
| Angle of half sensitivity      |                                                                                     | φ                 |      | ± 65                  |      | deg    |
| Wavelength of peak sensitivity |                                                                                     | λ <sub>p</sub>    |      | 950                   |      | nm     |
| Range of spectral bandwidth    |                                                                                     | λ <sub>0.5</sub>  |      | 790 to 1050           |      | nm     |
| Noise equivalent power         | $V_{R} = 10 \text{ V}, \lambda = 870 \text{ nm}$                                    | NEP               |      | 4 x 10 <sup>-14</sup> |      | W/√ Hz |
| Rise time                      | $V_R$ = 10 V, $R_L$ = 1 k $\Omega$ , $\lambda$ = 820 nm                             | t <sub>r</sub>    |      | 100                   |      | ns     |
| Fall time                      | $V_{R} = 10 \text{ V}, \text{ R}_{L} = 1 \text{ k}\Omega, \lambda = 820 \text{ nm}$ | t <sub>f</sub>    |      | 100                   |      | ns     |

Note

 $T_{amb}$  = 25 °C, unless otherwise specified

### **BASIC CHARACTERISTICS**

T<sub>amb</sub> = 25 °C, unless otherwise specified

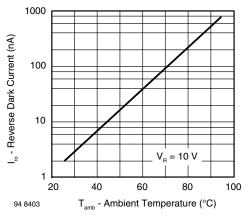


Fig. 1 - Reverse Dark Current vs. Ambient Temperature

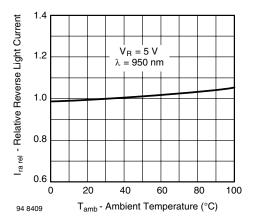


Fig. 2 - Relative Reverse Light Current vs. Ambient Temperature

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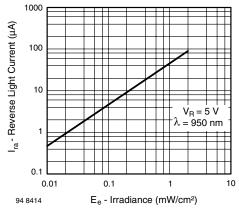


Fig. 3 - Reverse Light Current vs. Irradiance

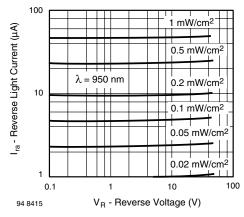


Fig. 4 - Reverse Light Current vs. Reverse Voltage

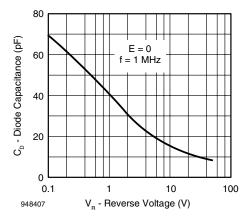


Fig. 5 - Diode Capacitance vs. Reverse Voltage

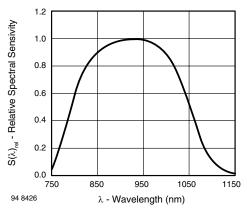


Fig. 6 - Relative Spectral Sensitivity vs. Wavelength

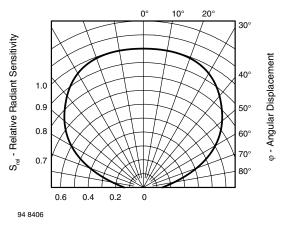


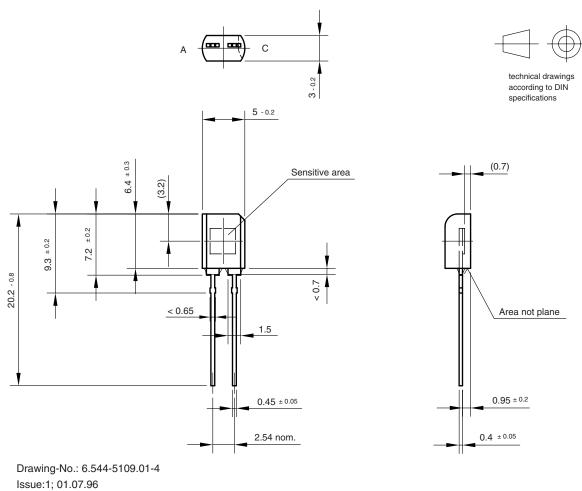
Fig. 7 - Relative Radiant Sensitivity vs. Angular Displacement



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## **PACKAGE DIMENSIONS** in millimeters



96 12196



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